



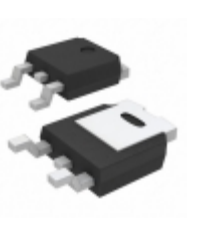

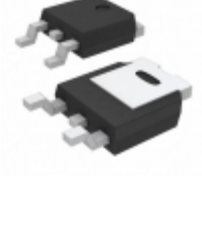


 life.augmented	Hersteller-Teilenummer: STD10NM60N
	Hersteller / Marke: STMicroelectronics
	Teil der Beschreibung: MOSFET N-CH 600V 10A DPAK
	Datenblätter:  STD10NM60N.pdf
RoHs Status: Bleifrei / RoHS-konform	Lagerzustand: New original, 6777 pcs Stock Available.
Lieferung von: Hong Kong	Versandweg: DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.	

Spezifikationen

Teilenummer	STD10NM60N
Hersteller	STMicroelectronics
Beschreibung	MOSFET N-CH 600V 10A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	6777 pcs Stock
Serie	MDmesh™ II
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	70W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	10A (Tc)
Rds On (Max) @ Id, Vgs	550 mOhm @ 4A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	19nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	540pF @ 50V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tape & Reel (TR)



















































STD10NM60N ist neu im Original, Suche STD10NM60N Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie STD10NM60N STMicroelectronics mit Garantie und Vertrauen.
Anfrage STD10NM60N: Info@Y-IC.com

Sie können auch interessiert sein:

 STD10NM60ND STMicroelectronics MOSFET N-CH 600V 8A DPAK	 STD10NF30 ST ST TO-252	 STD10NF10T4 STMicroelectronics MOSFET N-CH 100V 13A DPAK	 STD10NF30 STMicroelectronics MOSFET N-CHANNEL 300V 10A DPAK
 STD10P6F6 STMicroelectronics MOSFET P CH 60V 10A DPAK	 STD10NM50N STMicroelectronics MOSFET N-CH 500V 7A DPAK	 STD10NM60M2 ST ST TO252	 STD10PF06 ST STD10PF06 ST

heiße Teile

Mehr

 STD100N10LF7AG	 STD100N3LF3	 STD100NH02	 STD100NH02L	 STD100NH02L-06
 STD100NH02L-1	 STD100NH02LT4	 STD100NH03L	 STD100NH03L-06	 STD100NH03LT4
 STD1045T4	 STD1048T4	 STD1057T	 STD105N10F7AG	 STD10N10L
 STD10N60M2	 STD10NF06	 STD10NF06L	 STD10NF06LT4	 STD10NF06T4
 STD10NF10	 STD10NF10T4	 STD10NF30	 STD10NF30	 STD10NM50N
 STD10NM60ND	 STD10NM65N	 STD10P10F6	 STD10P6F6	 STD10PF06
 STD10PF06-1	 STD10PF06L	 STD10PF06T4	 STD110N8F6	 STD110NH02LT4
 STD116GK08	 STD116GK08B	 STD116GK12	 STD116GK12B	 STD116GK14
 STD116GK14B	 STD116GK16	 STD116GK16B	 STD116GK18	 STD116GK18B
 STD11N50M2	 STD11N65M2	 STD11N65M5	 STD11NM50N	 STD11NM60N

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